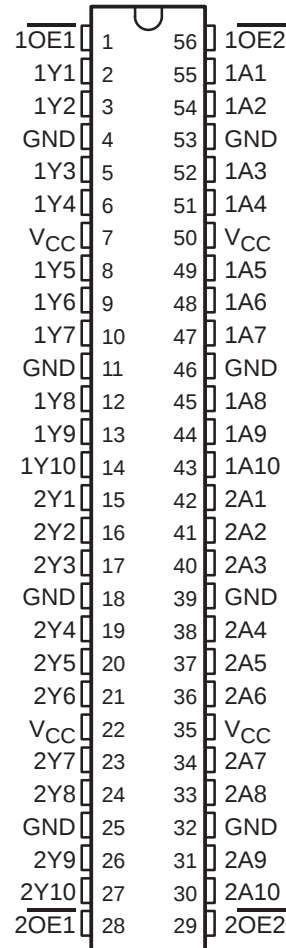


SN54ALVTH16827, SN74ALVTH16827 2.5-V/3.3-V 20-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCES076E – JULY 1996 – REVISED DECEMBER 1998

- State-of-the-Art Advanced BiCMOS Technology (ABT) *Widebus*™ Design for 2.5-V and 3.3-V Operation and Low Static Power Dissipation
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 2.3-V to 3.6-V V_{CC})
- Typical V_{OLP} (Output Ground Bounce) < 0.8 V at $V_{CC} = 3.3$ V, $T_A = 25^\circ\text{C}$
- High Drive ($-24/24$ mA at 2.5-V and $-32/64$ mA at 3.3-V V_{CC})
- Power Off Disables Outputs, Permitting Live Insertion
- High-Impedance State During Power Up and Power Down Prevents Driver Conflict
- Uses Bus Hold on Data Inputs in Place of External Pullup/Pulldown Resistors to Prevent the Bus From Floating
- Auto3-State Eliminates Bus Current Loading When Output Exceeds $V_{CC} + 0.5$ V
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model; and Exceeds 1000 V Using Charged-Device Model, Robotic Method
- Flow-Through Architecture Facilitates Printed Circuit Board Layout
- Distributed V_{CC} and GND Pin Configuration Minimizes High-Speed Switching Noise
- Package Options Include Plastic Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), Thin Very Small-Outline (DGV) Packages, and 380-mil Fine-Pitch Ceramic Flat (WD) Package

SN54ALVTH16827 . . . WD PACKAGE
SN74ALVTH16827 . . . DGG, DGV, OR DL PACKAGE
(TOP VIEW)



description

The 'ALVTH16827 devices are 20-bit buffers/line drivers designed for 2.5-V or 3.3-V V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

The devices are composed of two 10-bit sections with separate output-enable signals. For either 10-bit buffer section, the two output-enable ($1OE1$ and $1OE2$, or $2OE1$ and $2OE2$) inputs must be low for the corresponding Y outputs to be active. If either output-enable input is high, the outputs of that 10-bit buffer section are in the high-impedance state.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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SN54ALVTH16827, SN74ALVTH16827
2.5-V/3.3-V 20-BIT BUFFERS/DRIVERS
WITH 3-STATE OUTPUTS

SCES076E – JULY 1996 – REVISED DECEMBER 1998

description (continued)

When V_{CC} is between 0 and 1.2 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.2 V, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

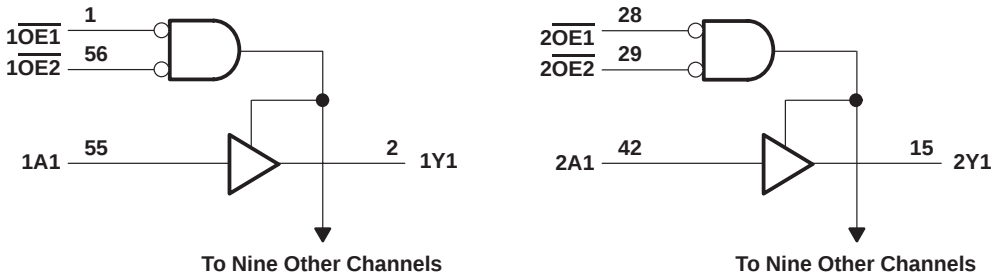
Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN54ALVTH16827 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74ALVTH16827 is characterized for operation from -40°C to 85°C .

FUNCTION TABLE
(each 10-bit section)

INPUTS			OUTPUT
$\overline{OE1}$	$\overline{OE2}$	A	Y
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}	$-0.5\text{ V to }4.6\text{ V}$
Input voltage range, V_I (see Note 1)	$-0.5\text{ V to }7\text{ V}$
Voltage range applied to any output in the high-impedance or power-off state, V_O (see Note 1)	$-0.5\text{ V to }7\text{ V}$
Voltage range applied to any output in the high state, V_O (see Note 1)	$-0.5\text{ V to }7\text{ V}$
Output current in the low state, I_O : SN54ALVTH16827	96 mA
SN74ALVTH16827	128 mA
Output current in the high state, I_O : SN54ALVTH16827	-48 mA
SN74ALVTH16827	-64 mA
Input clamp current, I_{IK} ($V_I < 0$)	-50 mA
Output clamp current, I_{OK} ($V_O < 0$)	-50 mA
Package thermal impedance, θ_{JA} (see Note 2): DGG package	81°C/W
DGV package	86°C/W
DL package	74°C/W
Storage temperature range, T_{stg}	$-65^{\circ}\text{C to }150^{\circ}\text{C}$

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. The package thermal impedance is calculated in accordance with JESD 51.

SN54ALVTH16827, SN74ALVTH16827
2.5-V/3.3-V 20-BIT BUFFERS/DRIVERS
WITH 3-STATE OUTPUTS

SCES076E – JULY 1996 – REVISED DECEMBER 1998

recommended operating conditions, $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$ (see Note 3)

		SN54ALVTH16827			SN74ALVTH16827			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
V_{CC}	Supply voltage	2.3		2.7	2.3		2.7	V
V_{IH}	High-level input voltage	1.7			1.7			V
V_{IL}	Low-level input voltage			0.7			0.7	V
V_I	Input voltage	0	V_{CC}	5.5	0	V_{CC}	5.5	V
I_{OH}	High-level output current			–6			–8	mA
I_{OL}	Low-level output current			6			8	mA
	Low-level output current; current duty cycle $\leq 50\%$; $f \geq 1\text{ kHz}$			18			24	
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled		10			10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate	200			200			$\mu\text{s/V}$
T_A	Operating free-air temperature	–55		125	–40		85	$^{\circ}\text{C}$

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

recommended operating conditions, $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ (see Note 3)

		SN54ALVTH16827			SN74ALVTH16827			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
V_{CC}	Supply voltage	3		3.6	3		3.6	V
V_{IH}	High-level input voltage	2			2			V
V_{IL}	Low-level input voltage			0.8			0.8	V
V_I	Input voltage	0	V_{CC}	5.5	0	V_{CC}	5.5	V
I_{OH}	High-level output current			–24			–32	mA
I_{OL}	Low-level output current			24			32	mA
	Low-level output current; current duty cycle $\leq 50\%$; $f \geq 1\text{ kHz}$			48			64	
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled		10			10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate	200			200			$\mu\text{s/V}$
T_A	Operating free-air temperature	–55		125	–40		85	$^{\circ}\text{C}$

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

SN54ALVTH16827, SN74ALVTH16827
2.5-V/3.3-V 20-BIT BUFFERS/DRIVERS
WITH 3-STATE OUTPUTS

SCES076E – JULY 1996 – REVISED DECEMBER 1998

electrical characteristics over recommended operating free-air temperature range,
 $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54ALVTH16827			SN74ALVTH16827			UNIT	
				MIN	TYP†	MAX	MIN	TYP†	MAX		
V _{IK}		V _{CC} = 2.3 V, I _I = −18 mA		−1.2			−1.2			V	
V _{OH}		V _{CC} = 2.3 V to 2.7 V, I _{OH} = −100 μA		V _{CC} −0.2			V _{CC} −0.2			V	
		V _{CC} = 2.3 V	I _{OH} = −6 mA	1.8							
			I _{OH} = −8 mA				1.8				
V _{OL}		V _{CC} = 2.3 V to 2.7 V, I _{OL} = 100 μA		0.2			0.2			V	
		V _{CC} = 2.3 V	I _{OL} = 6 mA	0.4			0.47				
			I _{OL} = 8 mA				0.4				
			I _{OL} = 18 mA	0.5							
			I _{OL} = 24 mA				0.5				
I _I	Control inputs	V _{CC} = 2.7 V, V _I = V _{CC} or GND		±1			±1			μA	
		V _{CC} = 0 or 2.7 V, V _I = 5.5 V		10			10				
	Data inputs	V _{CC} = 2.7 V	V _I = 5.5 V		10			10			
			V _I = V _{CC}		1			1			
			V _I = 0		−5			−5			
I _{off}		V _{CC} = 0, V _I or V _O = 0 to 4.5 V					±100			μA	
I _{BHL} ‡		V _{CC} = 2.3 V, V _I = 0.7 V		115			115			μA	
I _{BHH} §		V _{CC} = 2.3 V, V _I = 1.7 V		−10			−10			μA	
I _{BHLO} ¶		V _{CC} = 2.7 V, V _I = 0 to V _{CC}		300			300			μA	
I _{BHHO} #		V _{CC} = 2.7 V, V _I = 0 to V _{CC}		−300			−300			μA	
I _{EX}		V _{CC} = 2.3 V, V _O = 5.5 V		125			125			μA	
I _{OZ} (PU/PD)★		V _{CC} ≤ 1.2 V, V _O = 0.5 V to V _{CC} , V _I = GND or V _{CC} , $\overline{OE}$ = don't care		±100			±100			μA	
I _{OZH}		V _{CC} = 2.7 V	V _O = 2.3 V, V _I = 0.7 V or 1.7 V	5			5			μA	
I _{OZL}		V _{CC} = 2.7 V	V _O = 0.5 V, V _I = 0.7 V or 1.7 V	−5			−5			μA	
I _{CC}		V _{CC} = 2.7 V, I _O = 0, V _I = V _{CC} or GND	Outputs high	0.04	0.1	0.04		0.1	mA		
			Outputs low	2.3	5	2.3		5			
			Outputs disabled	0.04	0.1	0.04		0.1			
C _i		V _{CC} = 2.5 V, V _I = 2.5 V or 0		3			3			pF	
C _O		V _{CC} = 2.5 V, V _O = 2.5 V or 0		6			6			pF	

† All typical values are at $V_{CC} = 2.5\text{ V}$, $T_A = 25^\circ\text{C}$.

‡ The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

§ The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH} min.

¶ An external driver must source at least I_{BHLO} to switch this node from low to high.

An external driver must sink at least I_{BHLO} to switch this node from high to low.

|| Current into an output in the high state when $V_O > V_{CC}$

★ High-impedance state during power up or power down

SN54ALVTH16827, SN74ALVTH16827
2.5-V/3.3-V 20-BIT BUFFERS/DRIVERS
WITH 3-STATE OUTPUTS

SCES076E – JULY 1996 – REVISED DECEMBER 1998

electrical characteristics over recommended operating free-air temperature range,
 $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	SN54ALVTH16827			SN74ALVTH16827			UNIT
			MIN	TYP†	MAX	MIN	TYP†	MAX	
V_{IK}		$V_{CC} = 3\text{ V}$, $I_I = -18\text{ mA}$			-1.2			-1.2	V
V_{OH}		$V_{CC} = 3\text{ V to } 3.6\text{ V}$, $I_{OH} = -100\text{ }\mu\text{A}$	$V_{CC}-0.2$			$V_{CC}-0.2$			V
	$V_{CC} = 3\text{ V}$	$I_{OH} = -24\text{ mA}$	2						
		$I_{OH} = -32\text{ mA}$				2			
V_{OL}		$V_{CC} = 3\text{ V to } 3.6\text{ V}$, $I_{OL} = 100\text{ }\mu\text{A}$			0.2			0.2	V
	$V_{CC} = 3\text{ V}$	$I_{OL} = 16\text{ mA}$						0.4	
		$I_{OL} = 24\text{ mA}$			0.5				
		$I_{OL} = 32\text{ mA}$						0.5	
		$I_{OL} = 48\text{ mA}$			0.55				
		$I_{OL} = 64\text{ mA}$						0.55	
I_I	Control inputs	$V_{CC} = 3.6\text{ V}$, $V_I = V_{CC}\text{ or GND}$			± 1			± 1	μA
		$V_{CC} = 0\text{ or } 3.6\text{ V}$, $V_I = 5.5\text{ V}$			10			10	
	Data inputs	$V_{CC} = 3.6\text{ V}$, $V_I = 5.5\text{ V}$			10			10	
		$V_I = V_{CC}$			1			1	
		$V_I = 0$			-5			-5	
I_{off}		$V_{CC} = 0$, $V_I\text{ or } V_O = 0\text{ to } 4.5\text{ V}$						± 100	μA
$I_{BHL}^\ddagger$		$V_{CC} = 3\text{ V}$, $V_I = 0.8\text{ V}$	75			75			μA
$I_{BHH}^\S$		$V_{CC} = 3\text{ V}$, $V_I = 2\text{ V}$	-75			-75			μA
$I_{BHLO}^\P$		$V_{CC} = 3.6\text{ V}$, $V_I = 0\text{ to } V_{CC}$	500			500			μA
$I_{BHHO}^\#$		$V_{CC} = 3.6\text{ V}$, $V_I = 0\text{ to } V_{CC}$	-500			-500			μA
$I_{EX}^{ }$		$V_{CC} = 3\text{ V}$, $V_O = 5.5\text{ V}$			125			125	μA
$I_{OZ(PU/PD)}^\star$		$V_{CC} \leq 1.2\text{ V}$, $V_O = 0.5\text{ V to } V_{CC}$, $V_I = \text{GND or } V_{CC}$, $\overline{OE} = \text{don't care}$			± 100			± 100	μA
I_{OZH}		$V_{CC} = 3.6\text{ V}$, $V_O = 3\text{ V}$, $V_I = 0.8\text{ V or } 2\text{ V}$			5			5	μA
I_{OZL}		$V_{CC} = 3.6\text{ V}$, $V_O = 0.5\text{ V}$, $V_I = 0.8\text{ V or } 2\text{ V}$			-5			-5	μA
I_{CC}	$V_{CC} = 3.6\text{ V}$, $I_O = 0$, $V_I = V_{CC}\text{ or GND}$	Outputs high	0.07	0.1		0.07	0.1		mA
		Outputs low	3.2	6		3.2	6		
		Outputs disabled	0.07	0.1		0.07	0.1		
$\Delta I_{CC}^\square$		$V_{CC} = 3\text{ V to } 3.6\text{ V}$, One input at $V_{CC} - 0.6\text{ V}$, Other inputs at $V_{CC}\text{ or GND}$			0.4			0.4	mA
C_i		$V_{CC} = 3.3\text{ V}$, $V_I = 3.3\text{ V or } 0$			3			3	pF
C_o		$V_{CC} = 3.3\text{ V}$, $V_O = 3.3\text{ V or } 0$			6			6	pF

† All typical values are at $V_{CC} = 3.3\text{ V}$, $T_A = 25^\circ\text{C}$.

‡ The bus-hold circuit can sink at least the minimum low sustaining current at $V_{IL}\text{ max}$. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to $V_{IL}\text{ max}$.

§ The bus-hold circuit can source at least the minimum high sustaining current at $V_{IH}\text{ min}$. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to $V_{IH}\text{ min}$.

¶ An external driver must source at least I_{BHLO} to switch this node from low to high.

An external driver must sink at least I_{BHHO} to switch this node from high to low.

|| Current into an output in the high state when $V_O > V_{CC}$

☆ High-impedance state during power up or power down

□ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

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SN54ALVTH16827, SN74ALVTH16827
2.5-V/3.3-V 20-BIT BUFFERS/DRIVERS
WITH 3-STATE OUTPUTS

SCES076E – JULY 1996 – REVISED DECEMBER 1998

switching characteristics over recommended operating free-air temperature range, $C_L = 30$ pF, $V_{CC} = 2.5$ V $\pm$ 0.2 V (unless otherwise noted) (see Figure 1)

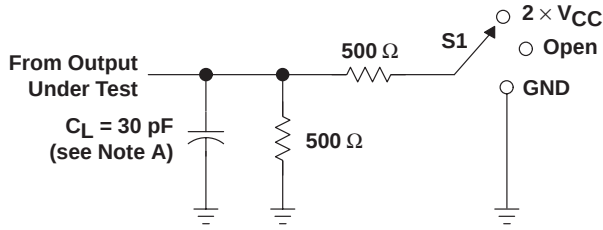
PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN54ALVTH16827		SN74ALVTH16827		UNIT
			MIN	MAX	MIN	MAX	
t_{PLH}	A	Y	1.5	3.2	1.5	3.2	ns
t_{PHL}			1.7	3.7	1.7	3.7	
t_{PZH}	$\overline{OE}$	Y	1.9	4.3	1.9	4.3	ns
t_{PZL}			1.8	4	1.8	4	
t_{PHZ}	$\overline{OE}$	Y	2.5	5.6	2.5	5.6	ns
t_{PLZ}			1.7	4.6	1.7	4.6	

switching characteristics over recommended operating free-air temperature range, $C_L = 50$ pF, $V_{CC} = 3.3$ V $\pm$ 0.3 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN54ALVTH16827		SN74ALVTH16827		UNIT
			MIN	MAX	MIN	MAX	
t_{PLH}	A	Y	1.8	3	1.8	3	ns
t_{PHL}			1.6	2.8	1.6	2.8	
t_{PZH}	$\overline{OE}$	Y	1.6	3.9	1.6	3.9	ns
t_{PZL}			1.5	3.4	1.5	3.4	
t_{PHZ}	$\overline{OE}$	Y	3.3	5.8	3.3	5.8	ns
t_{PLZ}			2.6	4.6	2.6	4.6	

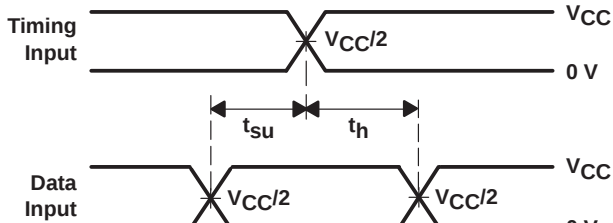
PARAMETER MEASUREMENT INFORMATION

$$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$$

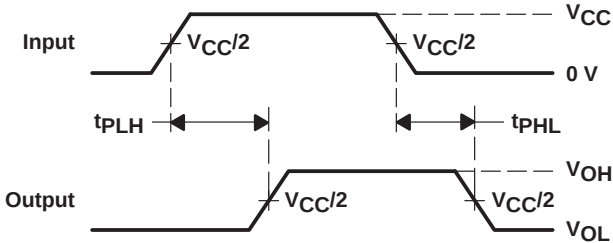


LOAD CIRCUIT

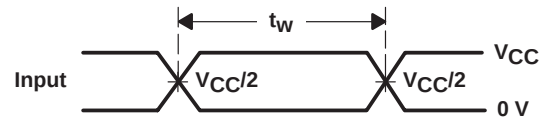
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	$2 \times V_{CC}$
t_{PHZ}/t_{PZH}	GND



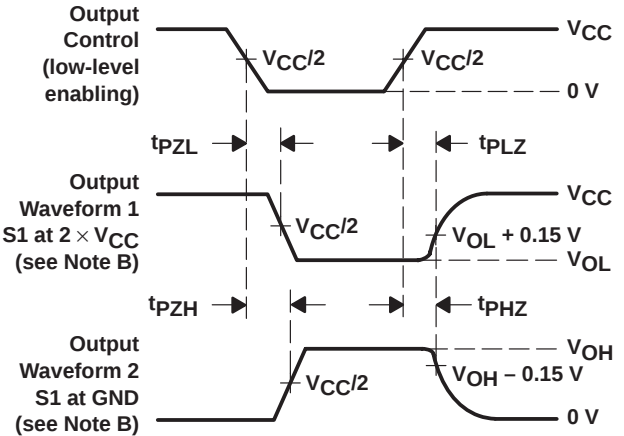
VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

- NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10\text{ MHz}$, $Z_O = 50\text{ }\Omega$, $t_r \leq 2\text{ ns}$, $t_f \leq 2\text{ ns}$.
D. The outputs are measured one at a time with one transition per measurement.

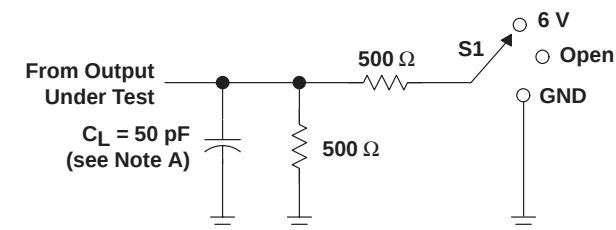
Figure 1. Load Circuit and Voltage Waveforms

SN54ALVTH16827, SN74ALVTH16827 2.5-V/3.3-V 20-BIT BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

SCES076E – JULY 1996 – REVISED DECEMBER 1998

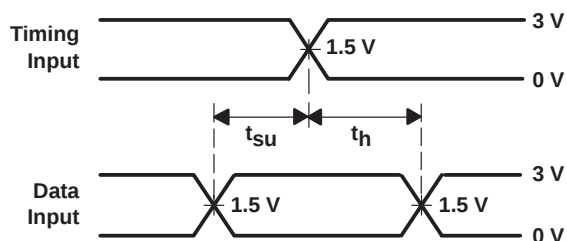
PARAMETER MEASUREMENT INFORMATION

$$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$$

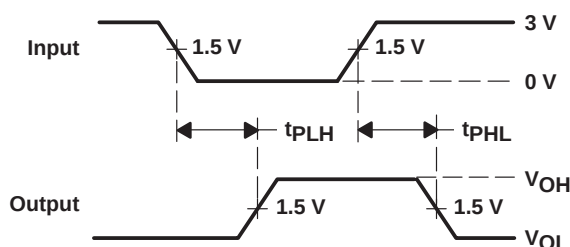


LOAD CIRCUIT

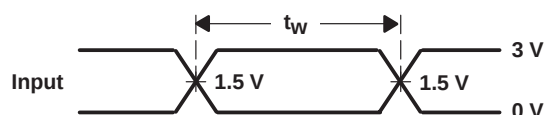
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	6 V
t_{PHZ}/t_{PZH}	GND



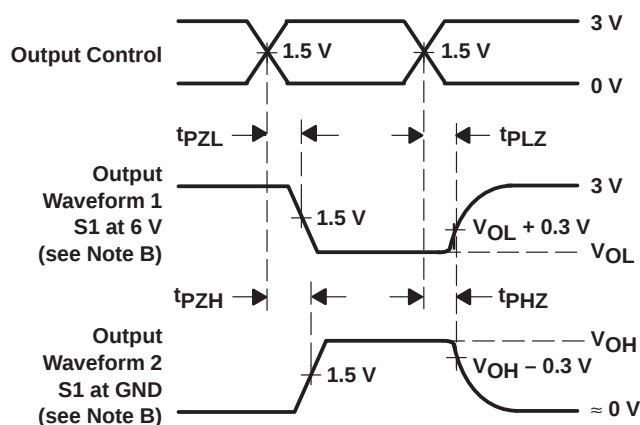
VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

- NOTES:
- A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2.5 \text{ ns}$, $t_f \leq 2.5 \text{ ns}$.
 - D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN74ALVTH16827DL	Obsolete	Production	SSOP (DL) 56	-	-	Call TI	Call TI	-40 to 85	ALVTH16827
SN74ALVTH16827DLR	Obsolete	Production	SSOP (DL) 56	-	-	Call TI	Call TI	-40 to 85	ALVTH16827
SN74ALVTH16827VR	Obsolete	Production	TVSOP (DGV) 56	-	-	Call TI	Call TI	-40 to 85	VT827

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

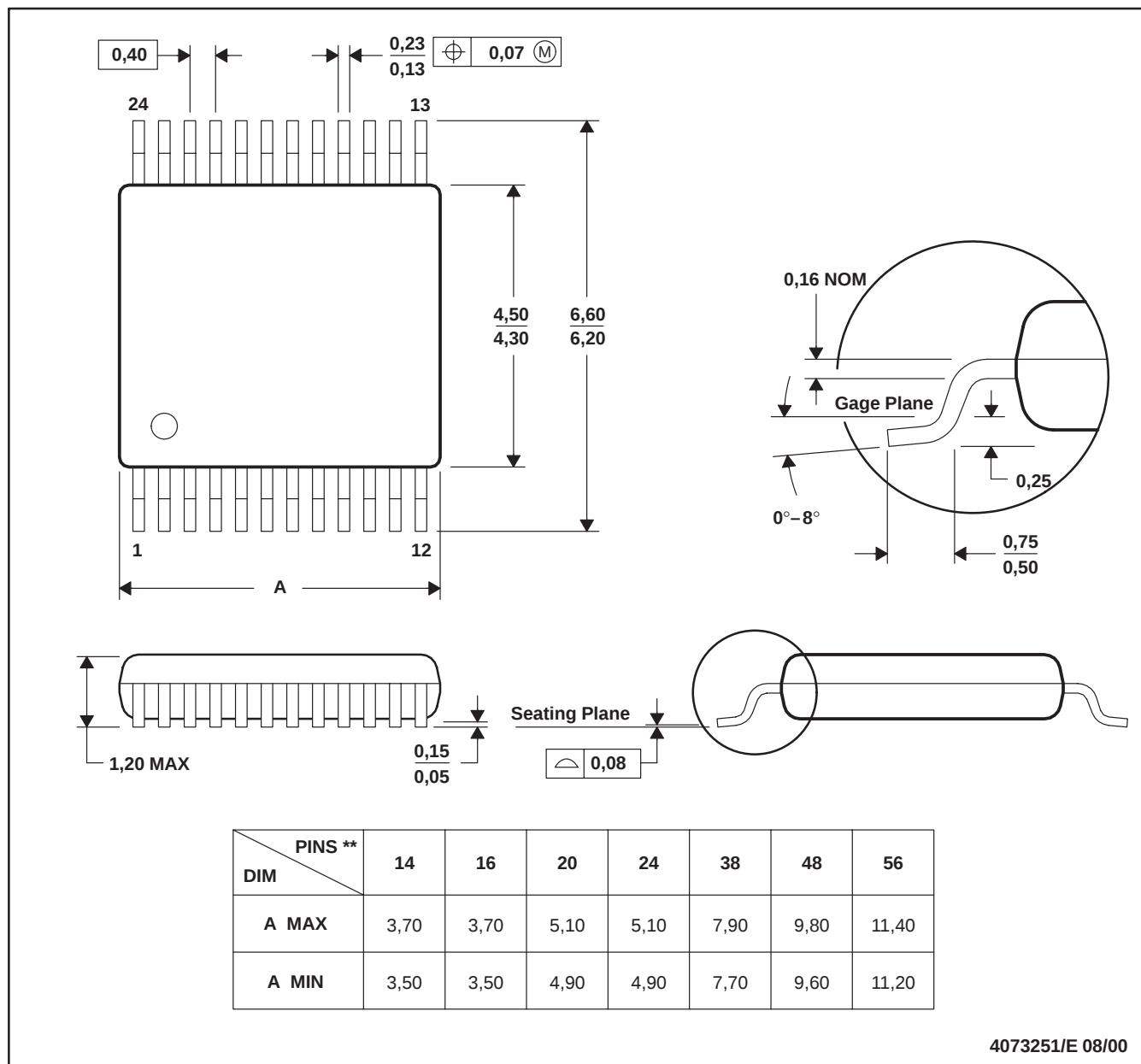
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DGV (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

24 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
 D. Falls within JEDEC: 24/48 Pins – MO-153
 14/16/20/56 Pins – MO-194



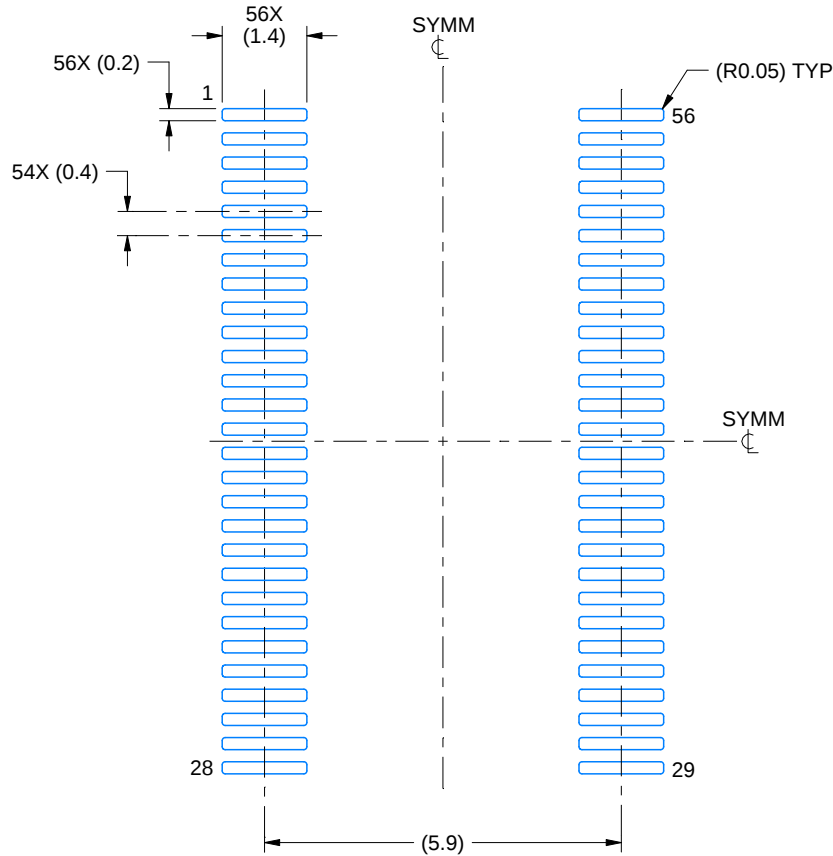
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-194.

EXAMPLE BOARD LAYOUT

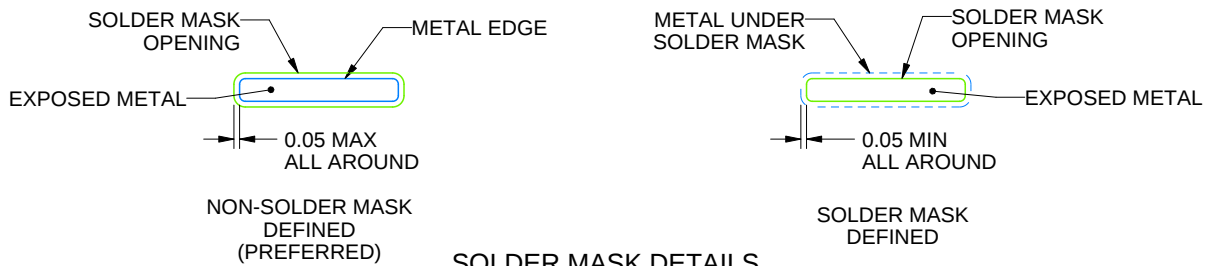
DGV0056A

TVSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 8X



SOLDER MASK DETAILS

4220240/B 12/2020

NOTES: (continued)

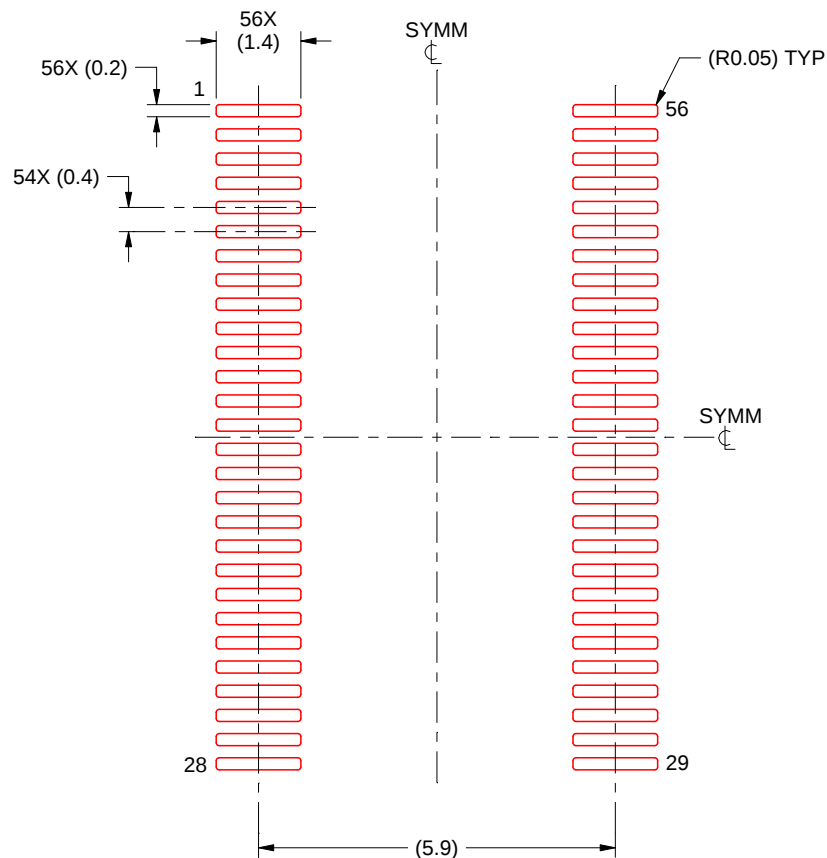
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DGV0056A

TVSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 8X

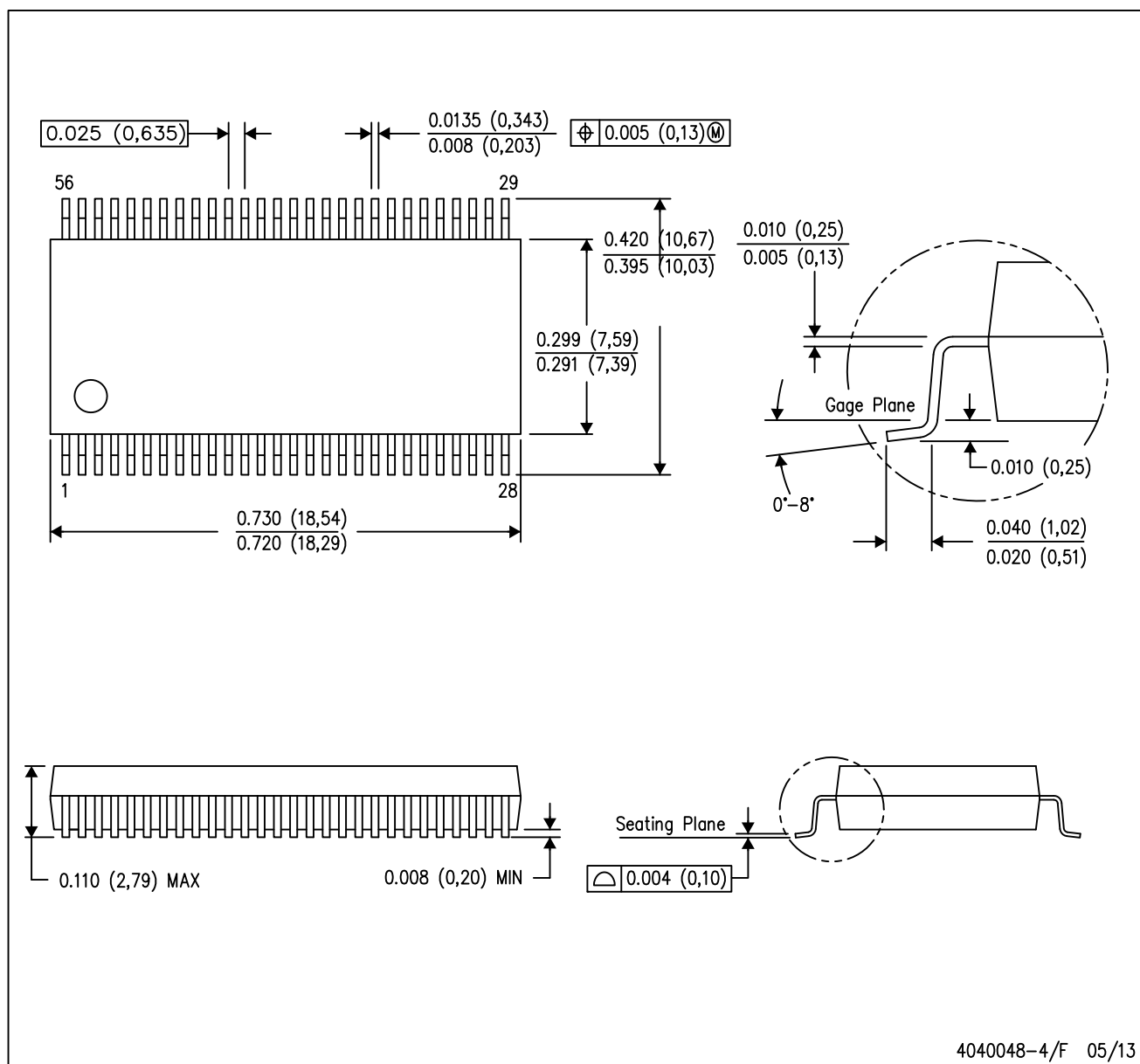
4220240/B 12/2020

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

DL (R-PDSO-G56)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- All linear dimensions are in inches (millimeters).
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- Falls within JEDEC MO-118

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